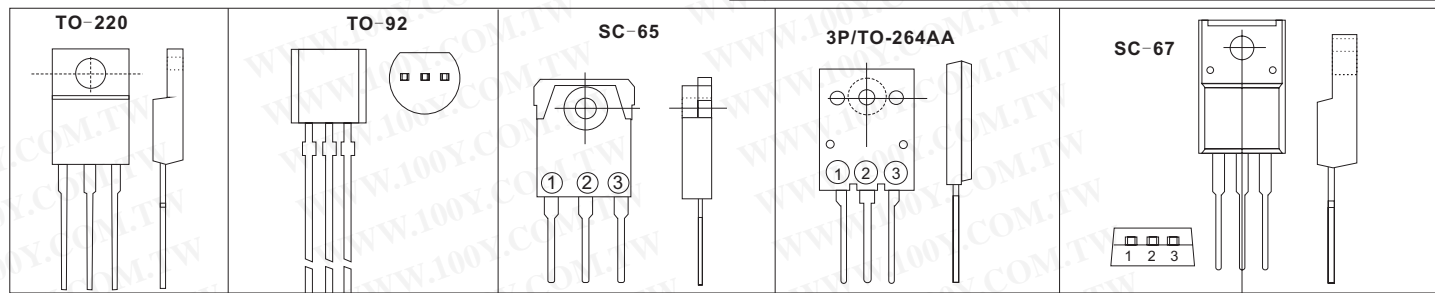


二极管+电晶体+模块

2SK~系列功率场效应电晶体

详细产品规格 - 请点击 cn.100y.com.tw



100Y 编号	厂商编号	制造厂商	说明	N/P Ch.	Pins/Package	Pd(max)	Vds	Vgss	Id(max)	Rds(on)(m ax.) Ω
14862	2SJ449	NEC	MOS FIELD EFFECT TRANSISTOR	P	3P/TO-220	35W	250V	±30V	6A	TO-220
15666	2SK1117	TOSHIBA	N-channel silicon power MOSFET	N	TO-220	100W	600V		6A	
15665	2SK1119	TOSHIBA	Silicon N channel field effect transistor for high speed, high current switching applications, DC-DC converter and motor drive applications	N	TO-220	100W	1000V	±20V	4A	
15664	2SK1507	FUJITSU	Fuji power MOS-FET	N	TO-220	50W	600V	±30V	9A	
32155	2SK1821	FUJITSU	N-channel power MOSFET	N	TO-220	30W	600V	±25V	2A	6.5
23663	2SK1994	NEC	Power MOSFET	N-CHANNEL	TO-220	30W		10V	2A	6.2
13607	2SK2134	NEC	N-channel power MOS FET for high voltage switching applications	N-Ch	TO-220	70W	10V	10V	7A	
17074	2SK2662	TOSHIBA	DC/DC Converter, Relay Drive and Motor Drive Applications	N	TO-220	35W	500V	±30V	5A	
39362	2SK525	TOSHIBA	Silicon N channel field effect transistor for high speed, high current switching applications, DC-DC converter and motor drive applications	N	TO-220	100W	1000V	±20V	4A	
28246	2SK2351	TOSHIBA	POWER MOSFETS CROSS REFERENCE	N	TO-220	80W	600	+ -30V	6	1.25
6026	2SK793	TOSHIBA	POWER MOSFET	N	3P/TO-220	150W	850V	±20V	5A	
14859	2SK513	HITACHI	Silicon N-Channel MOS FET	N	3P/TO-220	60W	800V	±20V	3A	
40034	2SJ74	Fairchild	P channel field effect transistor	P-Ch	TO-92	400mW	-10 V	25V	-1 mA	
20243	2SK1061	TOSHIBA	N channel field effect transistor	N-Ch.	3P/TO-92	300mW	60V	+/-20V	200mA	0.6Ω
6013	2SK117-GR	TOSHIBA	Silicon N Channel Junction Type	N	3P/TO-92	300mW	-50V	1.5V	10mA	
44794	2SK1221	NEC	功率场效应电晶体	PNP	TO-92	1	140			
39413	2SK1336	HITACHI	Silicon N-Channel MOS FET	N	TO-92	400 mW	60V	±20V	0.3A	
35862	2SK117	TOSHIBA	N CHANNEL JUNCTIONS	N	TO-92	0.3W		-50V	14mA	
40029	2SK170	TOSHIBA	N channel field effect transistor	N-Ch.	TO-92	400mW	10V	-30 V	10mA	
40381	2SK170GR	TOSHIBA	N channel field effect transistor	N-Ch.	TO-92	400mW	-40V		10mA	
4865	2SK30A-GR	TOSHIBA	N CHANNEL JUNCTION TYPE	N	3P/TO-92	100mW	-50V	-5V	2.6~6.5mA	
35876	2SK30ATM	TOSHIBA	N CHANNEL JUNCTION TYPE (LOW NOISE PRE-AMPLIFIER, TONE CONTROL AMPLIFIER AND DC-AC HIGH INPUT IMPEDANCE AMPLIFIER CIRCUIT APPLICATIONS)	N	TO-92	0.1W		-50V	6.5mA	
48242	2SK937	SANYO	High-Frequency General-Purpose Amplifier Applications	NP	TO-92	300mW	40V		100mA	
15942	2SK1017	Fuji Elect	N-channel silicon power MOSFET	N	3P/TO-3PN	150W	450V		20A	
15569	2SK1045	MITSUBIS HI	TRANSISTOR	N	3P/TO-3PN	150W	8000V	±30V	5A	
15657	2SK1081	Fairchild	N-channel silicon power MOSFET	N	TO-3P(N)	125W	800V	±30V	7A	
29187	2SK1082	FUJITSU	功率场效应电晶体	N Ch.	TO-3P/3PS	125W		+/-30V	18A	2.8
15127	2SK1120	TOSHIBA	Silicon N channel field effect transistor for high speed, high current switching applications, DC-DC converter and motor drive applications	N	3P/TO-3PN	150W	1000V	±20V	8A	
16620	2SK1339	HITACHI	High speed power switching	N	3P/TO-3PN	80W	900V	±30V	3A	
6033	2SK1341	HITACHI	Power switching MOSFET	N	3P/TO-3PN	100W	900V	±30V	6A	
19459	2SK1385	Fuji Elect	Power switching MOSFET	N	3P/TO-3PN	900mW	100V	±20V	600mA	
14856	2SK1403	HITACHI	Power switching MOSFET	N	3P/TO-3PN	100W	650V	±30V	±10μA	
6036	2SK1529		Silicon N channel field effect transistor for high power amplifier applications	N	3P/TO3PN	120W	180V	±20V	10A	
15646	2SK1940	Fuji Elect	power amplifier applications	N	3P/TO-3P	125W	600V	600V	12A	0.75
29186	2SK2488	NEC	功率场效应电晶体	N Ch.	TO-3P/3PS			+/-30V	+/-20A	1.2
39857	2SK2607	TOSHIBA	Silicon N Channel MOS Type (π?MOSIII)	N	TO-3P(N)	150W	800V	±30V	9A	1.2 Ω
28735	2SK2654	Fuji Elect	功率场效模块	N	3P/TO-3P	150W		±30V	8A	2Ω
10949	2SK2698	TOSHIBA	Silicon N channel field effect transistor	N	3P/TO3PN	150W	500V	±30V	1mA	
6024	2SK725	Fuji Elect	SILICON POWER MOS-FET	N	3P/TO-3PN	125W	500V	±20V	15mA	
15655	2SK727	FUJITSU	Power MOS-FET	N	TO-3P(N)	125W	900V	±20V	5A	
18466	2SK941	TOSHIBA	Power switching MOSFET	N	3P/TO-3PN	900mW	100V	±20V	600mA	
12674	2SK956		Power switching MOSFET	N	3P/TO-3PN	100W	900V	±30V	6A	
15658	2SK962	FUJITSU	N-channel	N	TO-3P(N)	150W	900V	±30V	8A	
15662	2SK1020	FUJITSU	N-channel silicon power MOSFET 无铅	N	3P/TO-264AA	300W	500V	±30V	30A	
29175	2SK1118	TOSHIBA	功率场效应电晶体	N Ch.	TO-220F	45W	600V	+/-30V	24A	1.25
17073	2SK2275	NEC	N-channel	N	TO-220F	35W	900V	10V	6A	
35875	2SK2843	TOSHIBA	N CHANNEL MOS TYPE (HIGH SPEED, HIGH CURRENT SWITCHING, CHOPPER REGULATOR, DC-DC CONVERTERAND MOTOR DRIVE APPLICATIONS)	N	SC-67	45W	600V	30V	10A	0.54 Ω



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